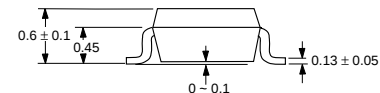
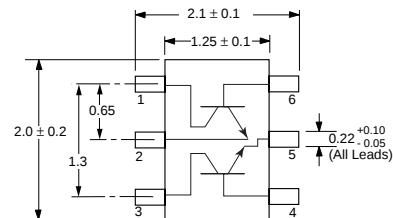


NEC**NPN SILICON EPITAXIAL TWIN TRANSISTOR****UPA835TF****FEATURES**

- **LOW NOISE:**
Q1: NF = 1.5 dB TYP at $f = 2$ GHz, $V_{CE} = 3$ V, $I_c = 3$ mA
Q2: NF = 1.2 dB TYP at $f = 1$ GHz, $V_{CE} = 3$ V, $I_c = 7$ mA
- **HIGH GAIN:**
Q1: $|S_{21E}|^2 = 8.5$ dB TYP at $f = 1$ GHz, $V_{CE} = 3$ V, $I_c = 10$ mA
Q2: $|S_{21E}|^2 = 9.0$ dB TYP at $f = 1$ GHz, $V_{CE} = 3$ V, $I_c = 7$ mA
- **6-PIN THIN-TYPE SMALL MINI MOLD PACKAGE**
- **2 DIFFERENT BUILT-IN TRANSISTORS**
(Q1: NE685, Q2: NE856)

DESCRIPTION

The UPA835TF has two different built-in transistors for low cost amplifier and oscillator applications in the VHF/UHF band. Low noise figures, high gain, high current capability, and medium output give this device high dynamic range and excellent linearity for two-stage amplifiers. This device is also ideally suited for use in a VCO/buffer amplifier application. The thinner package style allows for higher density designs.

OUTLINE DIMENSIONS (Units in mm)**Package Outline TS06 (Top View)****PIN CONNECTIONS**

1. Collector (Q1)
2. Emitter (Q1)
3. Collector (Q2)
4. Base (Q2)
5. Emitter (Q2)
6. Base (Q1)

Note:

Pin 1 is the lower left most pin as the package lettering is oriented and read left to right.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PART NUMBER PACKAGE OUTLINE				UPA835TF TS06		
	SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Q1	I_{CBO}	Collector Cutoff Current at $V_{CB} = 5$ V, $I_E = 0$	μA			0.1
	I_{EBO}	Emitter Cutoff Current at $V_{EB} = 1$ V, $I_C = 0$	μA			0.1
	h_{FE}	DC Current Gain ¹ at $V_{CE} = 3$ V, $I_c = 10$ mA		75		150
	f_T	Gain Bandwidth at $V_{CE} = 3$ V, $I_c = 10$ mA, $f = 2$ GHz	GHz		12	
	C_{re}	Feedback Capacitance ² at $V_{CB} = 3$ V, $I_E = 0$, $f = 1$ MHz	pF		0.4	0.7
	$ S_{21E} ^2$	Insertion Power Gain at $V_{CE} = 3$ V, $I_c = 10$ mA, $f = 2$ GHz	dB	7	8.5	
	NF	Noise Figure at $V_{CE} = 3$ V, $I_c = 3$ mA, $f = 2$ GHz	dB		1.5	2.5
Q2	I_{CBO}	Collector Cutoff Current at $V_{CB} = 10$ V, $I_E = 0$	μA			1.0
	I_{EBO}	Emitter Cutoff Current at $V_{EB} = 1$ V, $I_C = 0$	μA			1.0
	h_{FE}	DC Current Gain ¹ at $V_{CE} = 3$ V, $I_c = 7$ mA		100		145
	f_T	Gain Bandwidth at $V_{CE} = 3$ V, $I_c = 7$ mA, $f = 1$ GHz	GHz	3.0	4.5	
	C_{re}	Feedback Capacitance ² at $V_{CB} = 3$ V, $I_E = 0$, $f = 1$ MHz	pF		0.7	1.5
	$ S_{21E} ^2$	Insertion Power Gain at $V_{CE} = 3$ V, $I_c = 7$ mA, $f = 1$ GHz	dB	7	9	
	NF	Noise Figure at $V_{CE} = 3$ V, $I_c = 7$ mA, $f = 1$ GHz	dB		1.2	2.5

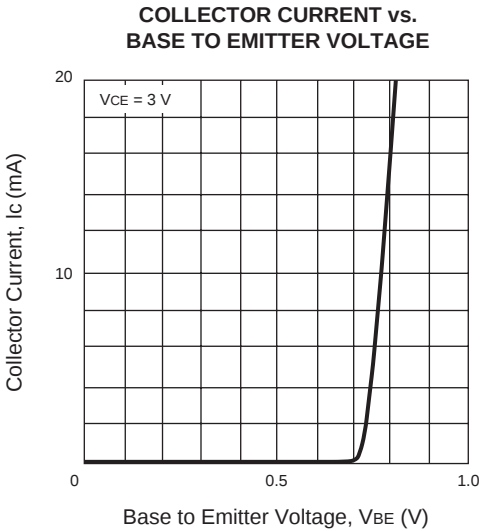
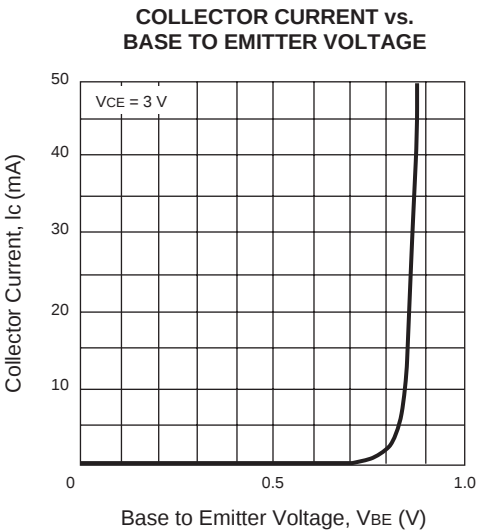
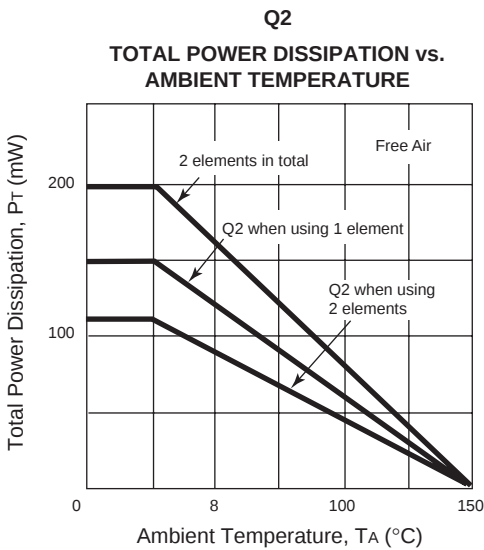
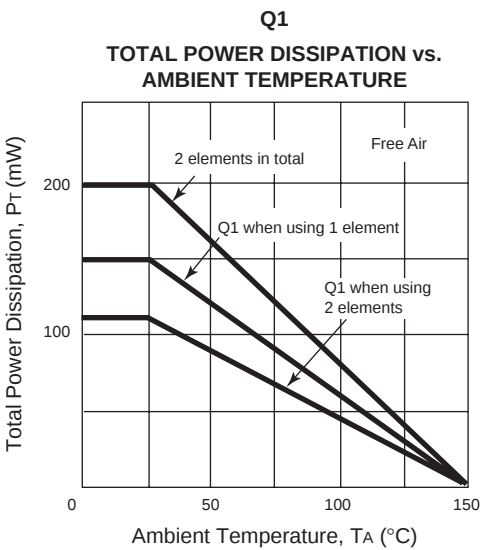
- Notes: 1. Pulsed measurement, pulse width ≤ 350 μs , duty cycle $\leq 2\%$.
2. Collector to base capacitance when measured with capacitance meter (automatic balanced bridge method), with emitter connected to guard pin of capacitances meter.

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS	
			Q1	Q2
V _{CBO}	Collector to Base Voltage	V	9	20
V _{CEO}	Collector to Emitter Voltage	V	6	12
V _{EBO}	Emitter to Base Voltage	V	2	3
I _C	Collector Current	mA	30	100
P _T	Total Power Dissipation	mW	150	150
			200 ²	
T _J	Junction Temperature	°C	150	150
T _{STG}	Storage Temperature	°C	-65 to +150	

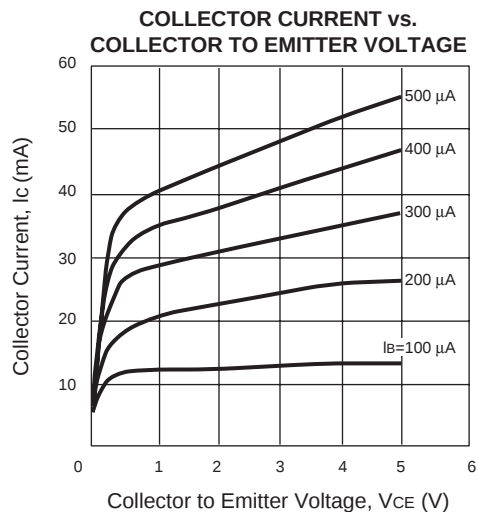
Note: 1. Operation in excess of any one of these parameters may result in permanent damage.
2. When operating both devices, the power dissipation for either device should not exceed 110 mW.

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

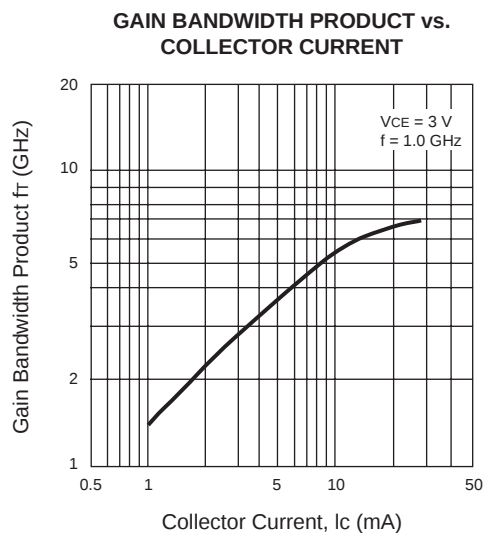
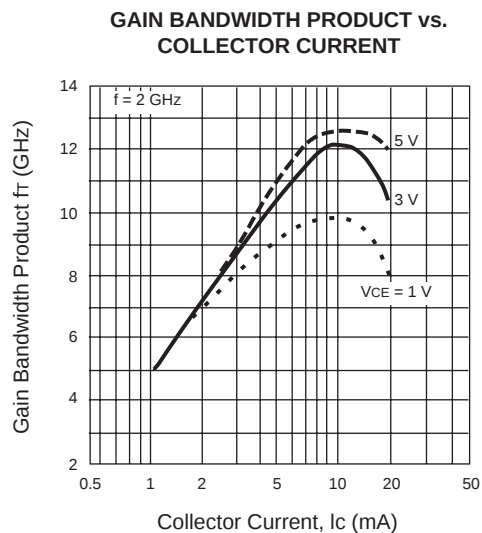
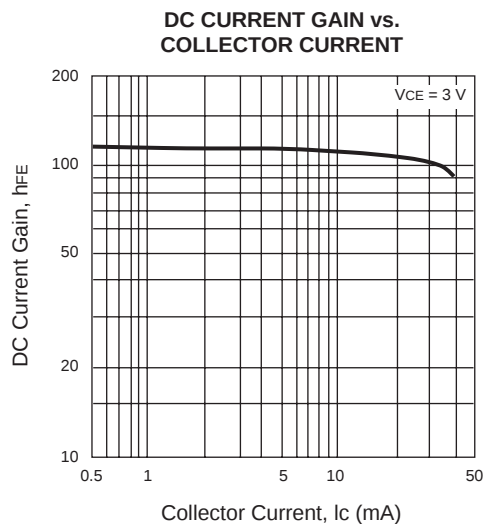
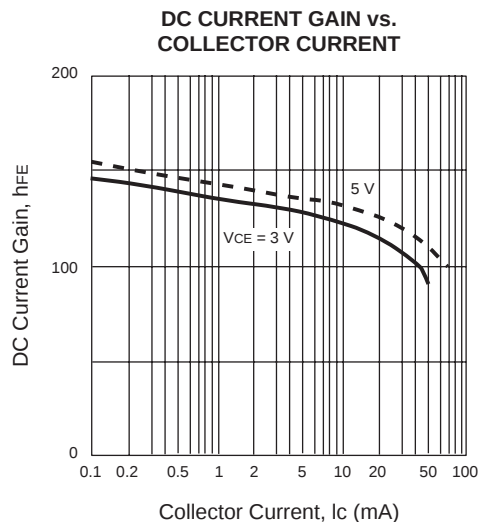
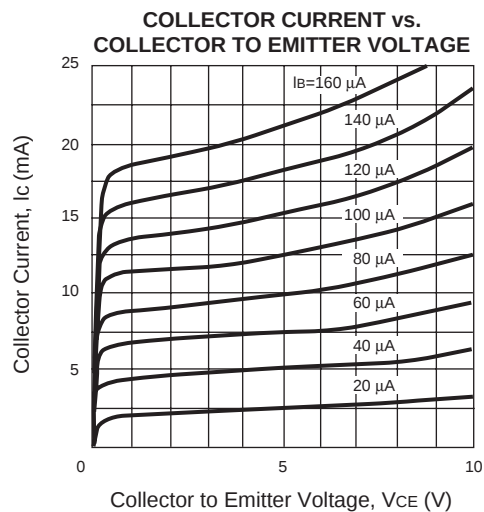


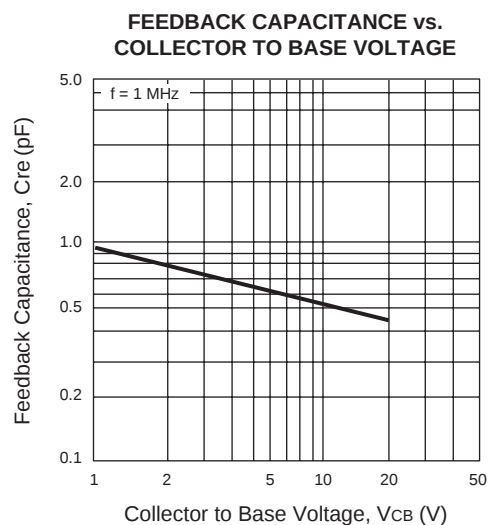
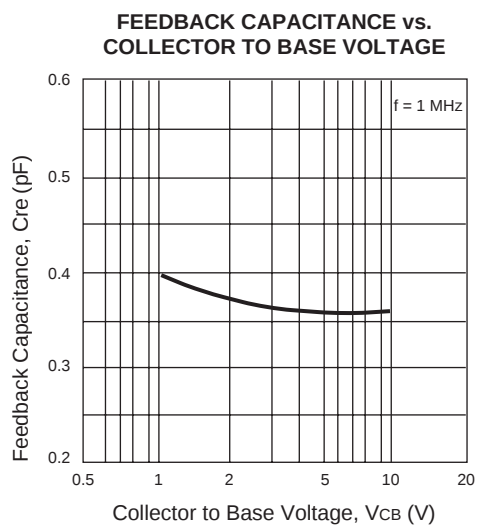
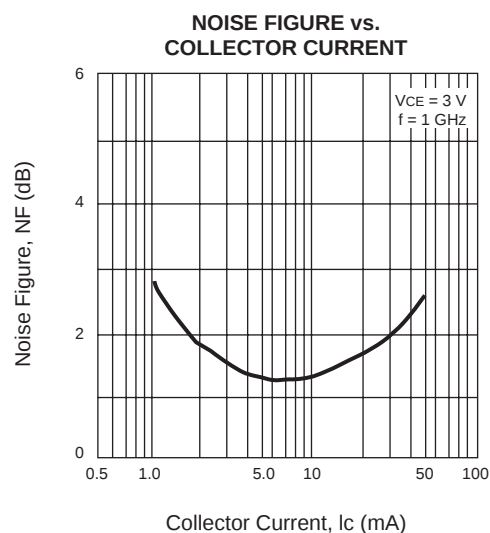
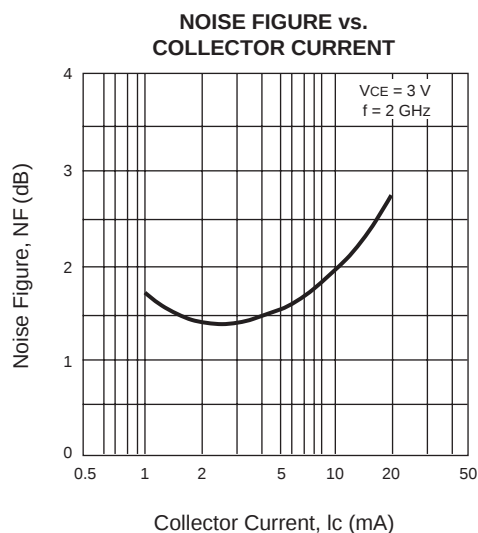
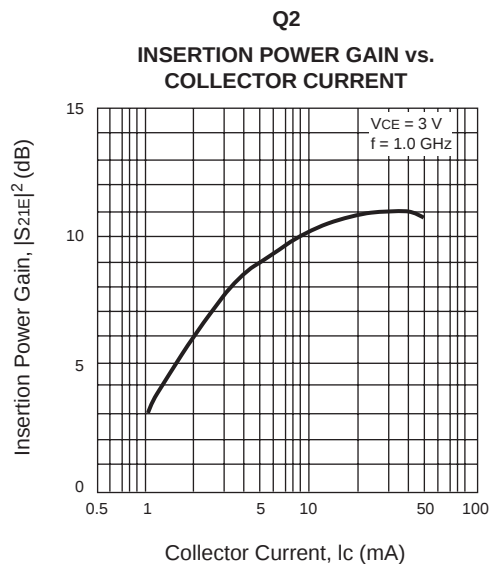
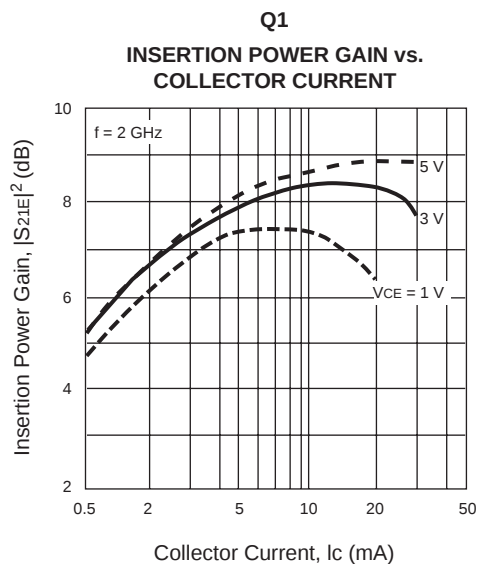
TYPICAL PERFORMANCE CURVES ($T_A = 25^\circ\text{C}$)

Q1

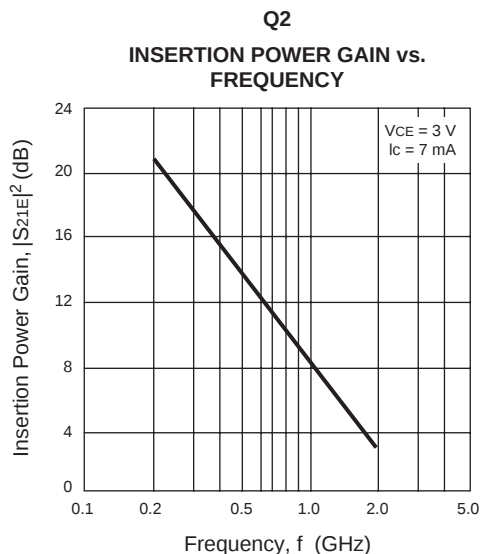


Q2



TYPICAL PERFORMANCE CURVES ($T_A = 25^\circ\text{C}$)

TYPICAL PERFORMANCE CURVES (T_A = 25°C)



TYPICAL SCATTERING PARAMETERS

Q1

VCE = 3 V, Ic = 1 mA, Z₀ = 50 Ω

FREQUENCY (GHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.98	-5.93	2.38	172.32	0.02	85.76	1.00	-3.86
0.20	0.97	-11.90	2.36	165.08	0.04	81.15	0.99	-7.44
0.30	0.95	-18.17	2.39	158.35	0.06	76.27	0.97	-11.14
0.40	0.93	-24.00	2.35	151.83	0.07	72.22	0.96	-14.73
0.50	0.90	-30.10	2.35	145.70	0.09	68.30	0.94	-18.02
0.60	0.87	-36.17	2.33	140.22	0.10	64.18	0.92	-21.42
0.70	0.84	-42.49	2.30	134.45	0.12	60.68	0.89	-24.18
0.80	0.80	-48.69	2.29	129.32	0.13	56.90	0.87	-27.47
0.90	0.76	-55.28	2.29	123.53	0.14	53.94	0.84	-29.94
1.00	0.73	-61.26	2.24	118.31	0.15	51.07	0.81	-32.50
1.20	0.64	-74.79	2.19	108.30	0.16	45.85	0.76	-36.89
1.50	0.51	-96.77	2.10	93.80	0.18	39.24	0.69	-42.90
1.70	0.43	-112.09	2.00	84.74	0.19	36.24	0.65	-46.39
2.00	0.35	-138.38	1.84	72.75	0.19	32.40	0.60	-51.51
2.50	0.31	175.03	1.62	54.64	0.20	29.55	0.53	-59.91
3.00	0.35	140.64	1.41	40.02	0.21	28.96	0.47	-69.74

Q2

VCE = 3 V, Ic = 1 mA, Z₀ = 50 Ω

FREQUENCY (GHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.97	-20.79	2.52	162.21	0.04	76.22	0.98	-8.81
0.20	0.93	-40.50	2.43	147.42	0.08	63.75	0.93	-16.39
0.30	0.89	-59.73	2.35	134.45	0.11	53.38	0.87	-22.34
0.40	0.84	-76.87	2.20	123.37	0.13	44.64	0.81	-27.24
0.50	0.80	-93.28	2.11	113.14	0.14	38.01	0.76	-30.90
0.60	0.76	-107.72	1.99	104.15	0.15	32.06	0.71	-34.29
0.70	0.74	-120.25	1.85	96.02	0.16	27.52	0.68	-36.96
0.80	0.71	-131.32	1.74	88.78	0.15	24.29	0.65	-39.46
0.90	0.69	-141.35	1.64	82.34	0.15	21.95	0.62	-41.97
1.00	0.68	-150.05	1.53	76.48	0.15	20.46	0.60	-44.52
1.20	0.67	-165.04	1.36	66.07	0.14	19.44	0.57	-50.06
1.50	0.67	176.90	1.17	52.95	0.13	24.64	0.53	-59.83
1.70	0.68	166.97	1.06	45.23	0.13	32.01	0.51	-68.26
2.00	0.69	154.69	0.94	35.40	0.14	44.56	0.48	-82.95
2.50	0.72	137.73	0.79	21.71	0.21	55.71	0.45	-114.70
3.00	0.75	124.46	0.68	11.96	0.30	51.65	0.46	-152.23

TYPICAL SCATTERING PARAMETERS

Q1

VCE = 3 V, IC = 3 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.94	-9.29	6.55	168.08	0.02	84.10	0.98	-6.91
0.20	0.90	-18.39	6.32	157.85	0.04	76.93	0.95	-13.21
0.30	0.85	-27.47	6.21	148.76	0.05	71.79	0.91	-18.80
0.40	0.80	-36.15	5.98	140.53	0.06	66.81	0.86	-23.80
0.50	0.74	-44.62	5.77	133.00	0.07	63.60	0.81	-27.41
0.60	0.67	-52.69	5.51	126.23	0.08	60.13	0.76	-31.19
0.70	0.60	-60.71	5.28	119.27	0.09	58.07	0.72	-33.67
0.80	0.54	-68.45	5.03	113.12	0.10	55.93	0.68	-36.31
0.90	0.47	-75.60	4.76	107.23	0.11	54.62	0.64	-38.10
1.00	0.42	-82.57	4.50	101.99	0.11	53.45	0.61	-39.74
1.20	0.32	-96.78	4.02	92.52	0.13	51.59	0.56	-42.63
1.50	0.21	-122.39	3.42	80.83	0.15	49.61	0.50	-46.74
1.70	0.17	-143.90	3.10	74.15	0.16	48.63	0.46	-49.50
2.00	0.16	179.12	2.70	64.83	0.18	46.70	0.42	-54.02
2.50	0.22	136.13	2.24	51.62	0.21	43.76	0.36	-63.34
3.00	0.29	115.80	1.89	39.81	0.23	40.27	0.31	-75.36

Q2

VCE = 3 V, IC = 3 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.90	-29.30	6.71	155.29	0.04	71.05	0.93	-16.80
0.20	0.82	-56.11	6.09	137.78	0.07	56.98	0.81	-28.76
0.30	0.73	-80.85	5.56	123.40	0.09	48.29	0.68	-35.65
0.40	0.67	-101.56	4.95	111.97	0.10	42.87	0.59	-40.13
0.50	0.62	-118.49	4.38	102.51	0.11	39.94	0.52	-42.64
0.60	0.59	-131.80	3.86	94.93	0.11	38.27	0.47	-44.51
0.70	0.57	-142.87	3.44	88.40	0.11	37.56	0.43	-45.87
0.80	0.56	-152.14	3.11	82.68	0.12	37.77	0.40	-47.30
0.90	0.55	-159.99	2.82	77.69	0.12	38.47	0.38	-48.65
1.00	0.54	-168.88	2.59	73.06	0.13	39.41	0.36	-50.22
1.20	0.55	-178.59	2.21	64.68	0.13	41.56	0.32	-54.00
1.50	0.56	167.41	1.84	53.63	0.15	45.41	0.28	-62.05
1.70	0.57	159.71	1.66	46.97	0.17	47.04	0.25	-70.04
2.00	0.60	149.93	1.45	37.59	0.19	48.39	0.22	-85.71
2.50	0.64	136.23	1.20	23.63	0.25	47.57	0.19	-125.28
3.00	0.68	125.06	1.02	11.49	0.31	42.77	0.23	-169.77

TYPICAL SCATTERING PARAMETERS

Q1

VCE = 3 V, IC = 5 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.90	-12.12	10.05	165.07	0.02	82.08	0.97	-9.12
0.20	0.84	-23.51	9.49	152.86	0.03	74.99	0.92	-17.06
0.30	0.77	-34.84	9.08	142.06	0.05	69.42	0.85	-23.23
0.40	0.69	-45.03	8.52	132.57	0.06	65.57	0.78	-28.22
0.50	0.60	-54.58	7.94	123.96	0.07	63.02	0.72	-31.57
0.60	0.52	-62.89	7.32	116.79	0.08	60.80	0.66	-34.45
0.70	0.44	-70.48	6.74	109.99	0.08	59.78	0.62	-36.34
0.80	0.38	-77.63	6.21	104.22	0.09	58.73	0.58	-38.08
0.90	0.32	-84.12	5.71	99.08	0.10	57.98	0.55	-39.38
1.00	0.28	-90.92	5.28	94.41	0.11	57.45	0.53	-40.58
1.20	0.20	-105.44	4.56	86.53	0.12	56.41	0.48	-42.73
1.50	0.13	-137.90	3.78	76.56	0.14	54.85	0.43	-46.37
1.70	0.11	-167.88	3.39	70.79	0.15	53.69	0.40	-49.23
2.00	0.13	152.80	2.93	62.58	0.18	51.42	0.37	-54.00
2.50	0.21	121.76	2.41	50.64	0.21	47.56	0.31	-64.32
3.00	0.28	107.74	2.03	39.80	0.24	42.91	0.26	-78.22

Q2

VCE = 3 V, IC = 5 mA, Z0 = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.83	-36.95	10.41	149.93	0.04	67.41	0.87	-23.15
0.20	0.72	-69.61	9.00	130.38	0.06	54.36	0.70	-36.92
0.30	0.62	-97.36	7.70	115.33	0.07	48.48	0.56	-43.33
0.40	0.56	-117.96	6.47	104.59	0.08	46.08	0.46	-46.73
0.50	0.53	-133.20	5.47	96.45	0.09	45.55	0.40	-48.28
0.60	0.51	-145.02	4.72	89.97	0.10	45.75	0.35	-49.37
0.70	0.50	-154.27	4.13	84.56	0.10	46.29	0.32	-50.23
0.80	0.49	-162.17	3.68	79.59	0.11	47.21	0.29	-50.94
0.90	0.49	-168.79	3.31	75.30	0.12	48.13	0.27	-51.90
1.00	0.49	-174.60	3.02	71.24	0.13	48.87	0.25	-53.05
1.20	0.50	175.37	2.56	63.72	0.14	49.97	0.22	-56.22
1.50	0.52	163.26	2.11	53.63	0.17	50.87	0.18	-64.21
1.70	0.53	156.57	1.90	47.43	0.19	50.65	0.15	-73.44
2.00	0.56	147.71	1.65	38.70	0.22	49.28	0.11	-94.06
2.50	0.61	135.31	1.36	25.02	0.27	45.44	0.11	-153.25
3.00	0.66	124.98	1.16	13.38	0.32	39.42	0.18	-163.89

TYPICAL SCATTERING PARAMETERS

Q1

VCE = 3 V, IC = 10 mA, ZO = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.82	-17.52	16.52	159.99	0.02	80.28	0.94	-12.68
0.20	0.72	-33.22	14.93	144.21	0.03	72.82	0.85	-22.43
0.30	0.60	-46.83	13.32	131.03	0.04	68.07	0.75	-28.43
0.40	0.49	-57.62	11.65	120.45	0.05	65.62	0.67	-32.14
0.50	0.40	-65.90	10.15	112.22	0.06	65.03	0.60	-34.25
0.60	0.33	-72.93	8.90	105.92	0.07	63.86	0.56	-35.78
0.70	0.27	-79.33	7.89	100.37	0.08	63.74	0.52	-36.80
0.80	0.22	-85.38	7.07	95.73	0.08	63.50	0.49	-37.69
0.90	0.18	-91.73	6.39	91.61	0.09	63.16	0.46	-38.46
1.00	0.15	-98.81	5.83	87.88	0.10	62.77	0.45	-39.30
1.20	0.10	-118.22	4.95	81.32	0.11	61.85	0.41	-41.01
1.50	0.07	-176.19	4.05	72.83	0.14	59.79	0.38	-44.69
1.70	0.08	149.79	3.61	67.81	0.15	58.31	0.35	-47.69
2.00	0.13	125.94	3.12	60.46	0.18	55.55	0.32	-53.15
2.50	0.21	109.57	2.54	49.58	0.22	50.37	0.27	-65.07
3.00	0.29	100.79	2.14	39.46	0.25	45.03	0.21	-81.46

Q2

VCE = 3 V, IC = 7 mA, ZO = 50 Ω

FREQUENCY (GHz)	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.10	0.78	-43.98	13.56	145.65	0.04	65.30	0.83	-28.08
0.20	0.64	-81.06	11.15	124.63	0.05	53.73	0.62	-42.31
0.30	0.55	-109.37	9.00	109.90	0.07	50.12	0.47	-48.09
0.40	0.50	-128.61	7.29	100.27	0.07	49.49	0.39	-50.66
0.50	0.48	-142.36	6.05	93.07	0.08	50.25	0.33	-51.72
0.60	0.47	-152.78	5.16	87.38	0.09	50.94	0.29	-52.25
0.70	0.46	-161.04	4.49	82.41	0.10	51.76	0.26	-52.80
0.80	0.46	-168.03	3.98	77.92	0.11	52.62	0.23	-53.35
0.90	0.46	-173.82	3.57	74.02	0.12	53.24	0.21	-54.00
1.00	0.46	-179.09	3.24	70.24	0.13	53.84	0.19	-55.03
1.20	0.47	171.98	2.75	63.22	0.15	53.97	0.15	-58.07
1.50	0.50	160.99	2.25	53.72	0.18	53.24	0.18	-66.67
1.70	0.51	154.69	2.02	47.63	0.20	52.05	0.20	-78.75
2.00	0.54	146.49	1.75	39.20	0.23	49.60	0.23	-110.79
2.50	0.59	134.74	1.44	26.11	0.28	44.37	0.28	174.41
3.00	0.64	124.73	1.23	14.52	0.33	38.05	0.33	146.24

BUILT-IN TRANSISTORS

	Q1	Q2
3-pin small mini mold part No.	NE68530	NE85630

ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
UPA835TF-T1	3000	Tape & Reel

The UPA832TF features the Q1 and Q2 in inverted positions.

BJT NONLINEAR MODEL PARAMETERS⁽¹⁾

Parameters	Q1	Q2	Parameters	Q1	Q2
IS	7e-16	6e-16	MJC	0.34	0.55
BF	109	120	XCJC	0	0.3
NF	1	0.98	CJS	0	0
VAF	15	10	VJS	0.75	0.75
IKF	0.19	0.08	MJS	0	0
ISE	7.9e-13	32e-16	FC	0.5	0.5
NE	2.19	1.93	TF	2.5e-12	12e-12
BR	1	12	XTF	5.2	6
NR	1.08	0.991	VTF	4.58	10
VAR	12.4	3.9	ITF	0.01	0.2
IKR	Infinity	0.17	PTF	0	0
ISC	0	0	TR	1e-9	1e-9
NC	2	2	EG	1.11	1.11
RE	1.3	0.38	XTB	0	0
RB	10	4.16	XTI	3	3
RBM	8.34	3.6	KF	0	0
IRB	0.009	1.96e-4	AF	1	1
RC	10	2			
CJE	0.4e-12	2.8e-12			
VJE	0.81	1.3			
MJE	0.5	0.5			
CJC	0.18e-12	1.1e-12			
VJC	0.75	0.7			

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

MODEL RANGE

Frequency: 0.1 to 3.0 GHz
Bias: $V_{CE} = 0.5\text{ V to }5\text{ V}$, $I_C = 1\text{ mA to }10\text{ mA}$
Date: 11/98

Note:

This nonlinear model utilized the latest data available. See our Design Parameter Library at www.cel.com for this data.



Frequency: 0.1 to 3.0 GHz
Bias: $V_{CE} = 0.5 \text{ V to } 5 \text{ V}$, $I_c = 1 \text{ mA to } 10 \text{ mA}$
Date: 11/98

	Q1	Q2
3-pin small mini mold part No.	NE68530	NE85630

PART NUMBER	QUANTITY	PACKAGING
UPA835TF-T1	3000	Tape & Reel

The UPA832TF features the Q1 and Q2 in inverted positions.